

2.5V Drive Nch MOSFET

RK7002B

Structure

Silicon N-channel MOSFET

Features

- 1) High speed switing.
- 2) Small package(SST3).
- 3) Low voltage drive(2.5V drive).

Application

Switching

Packaging specifications

	Package	Taping	
Type	Code	T116	
	Basic ordering unit (pieces)	3000	
RK7002B		0	

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit				
Drain-source voltage		V_{DSS}	60	V				
Gate-source voltage		V_{GSS}	±20	V				
Drain current	Continuous	I _D	±250	mA				
	Pulsed	I _{DP} *1	±1	Α				
Source current	Continuous	Is	150	mA				
(Body Diode)	Pulsed	I _{SP} *1	1	Α				
Total power dissipation		P _D *2	0.2	W				
Channel temperature		Tch	150	°C				
Range of storage temperature		Tstg	-55 to +150	°C				

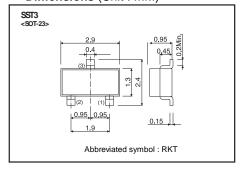
^{*1} Pw≤10µs, Duty cycle≤1%

Thermal resistance

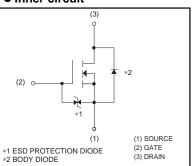
Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a)*	625	°C/W

^{*} Each terminal mounted on a recommended land.

● Dimensions (Unit : mm)



• Inner circuit



^{*2} Each terminal mounted on a recommended land.

RK7002B Data Sheet

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	1	-	±10	μA	$V_{GS}=\pm20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	-	-	٧	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	1	-	1	μA	V_{DS} =60V, V_{GS} =0V
Gate threshold voltage	V _{GS (th)}	1.0	-	2.3	٧	V_{DS} =10V, I_{D} =1mA
		1	1.7	2.4	Ω	$I_D = 250 \text{mA}, V_{GS} = 10 \text{V}$
Static drain-source on-state	D *	1	2.1	3.0		I _D =250mA, V _{GS} =4.5V
resistance	R _{DS (on)}	1	2.3	3.2		I _D =250mA, V _{GS} =4.0V
		1	3.0	12.0		I _D =10mA, V _{GS} =2.5V
Forward transfer admittance	IY _{fs} I*	0.25	-	-	S	I _D =250mA, V _{DS} =10V
Input capacitance	C _{iss}	1	15	-	pF	V _{DS} =25V
Output capacitance	C _{oss}	1	4.5	-	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}		2	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	-	3.5	-	ns	I _D =100mA, V _{DD} ≒ 30V
Rise time	t _r *	-	5	-	ns	V _{GS} =10V
Turn-off delay time	t _{d(off)} *	1	18	-	ns	R _L ≒300Ω
Fall time	t _f *	-	28	-	ns	$R_G=10\Omega$

^{*}Pulsed

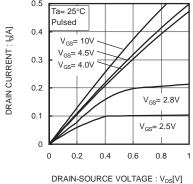
●Body diode characteristics (Source-Drain) (Ta = 25°C)

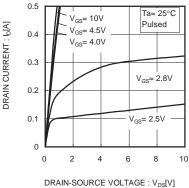
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	-	-	1.2	V	I _s =250mA, V _{GS} =0V

^{*}Pulsed

RK7002B Data Sheet

Electrical characteristics curves





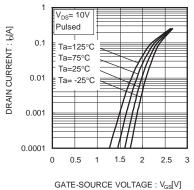
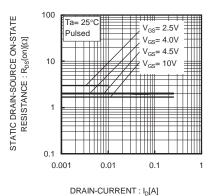


Fig.1 Typical Output Characteristics(I)

Fig.2 Typical Output Characteristics(II)

Fig.3 Typical Transfer Characteristics



 ${\tt STATIC DRAIN-SOURCE ON-STATE} \\ {\tt RESISTANCE: R}_{DS}(on)[\Omega]$ V_{GS}= 10V Ta=125°C Ta=75°C Ta=25°C 10 Ta= -25°C 0.1 0.001 0.01 0.1

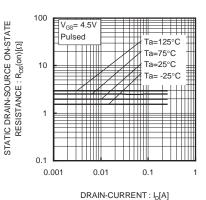
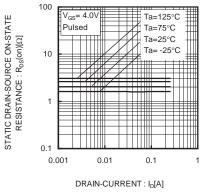
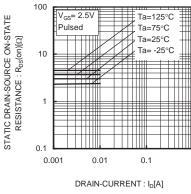


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

DRAIN-CURRENT : I_D[A] Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)





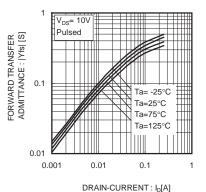
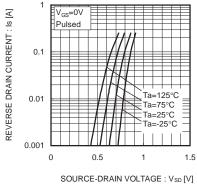


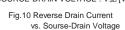
Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(IV)

Fig.9 Forward Transfer Admittance vs. Drain Current

RK7002B Data Sheet





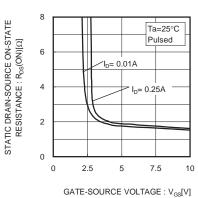


Fig.11 Static Drain-Source On-State Resistance vs. Gate Source Voltage

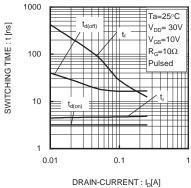
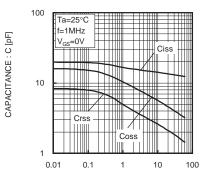


Fig.12 Switching Characteristics



DRAIN-SOURCE VOLTAGE: VDs[V]
Fig.13 Typical Capacitance
vs. Drain-Source Voltage

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●Measurement circuits

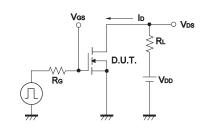


Fig.1-1 Switching time measurement circuit

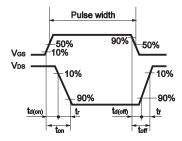


Fig.1-2 Switching waveforms

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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